## MB05F thru MB10F

### Miniature Glass Passivated Single-Phase Surface Mount Flat Bridge Rectifier

#### **VOLTAGE - 50 TO 1000 VOLTS CURRENT - 0.5 AMPERES**

**Major Ratings and Characteristics** 

I <sub>F(AV)</sub>	0.5A , 0.8A
$V_{RRM}$	50-1000V
I <sub>FSM</sub>	35 A
I <sub>R</sub>	5.0 μΑ
$V_{F}$	1.0V
T <sub>j</sub> max.	150 °C

#### FEATURES

- Low profile space
- · Ideal for automated placement
- Glass passivated chip junction
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High temperature soldering: 260 °C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/1 and WEEE 2002/96/EC

# 5.6(0.220) 6.0(0.236) 5.0(0.197) 2.3(0.090) 2.7(0.106) 0.1(0.004)0.5(0.020)0.3(0.012) max 0.1(0.004) 1.1(0.043) 6.6(0.260) 7.0(0.276)

**MBF** 

Dimensions in millimeters and (inches)

#### MECHANICAL DATA

- Case: MBF Molded plastic over glass passivated chip
- Terminals: Solder plated, solderable per J-STD-002B and JESD22-B102D
- Polarity: Polarity symbols marked on body

## MAXIMUM RATIXGS AND ELECTRICAL CHARACTERISTICS

(T<sub>A</sub> = 25 °C unless otherwise noted)

		Symbol	MB05F	MB1F	MB2F	MB4F	MB6F	MB8F	MB10F	UNIT
Maximum repetitive peak reverse voltage		$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage		$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage		$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward output rectified current at T <sub>A</sub> =30℃ -on glass-epoxy P.C.B(NOTE 1) -on aluminum substrate(NOTE 2)		I <sub>F(AV)</sub>	0.5 0.8							Α
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load(JEDEC Method)		I <sub>FSM</sub>	35							Α
Maximum instantaneous forwad voltage drop per leg at 0.4A		$V_{F}$	1							V
Maximum DC reverse current at $T_A = 25 ^{\circ}\text{C}$ rated DC blocking voltage per leg $T_A = 125 ^{\circ}\text{C}$		I <sub>R</sub>	5.0 100							μА
Typical junction capacitance per leg at 4.0 V ,1MHz		CJ	13						рF	
Thermal resistance per leg	(NOTE 1) (NOTE 2) (NOTE 1)	$R_{\theta JA} \ R_{\theta JA} \ R_{\theta JL}$				85 70 20				°C/W
Operating junction and storage temperature range		$T_J$ , $T_{STG}$	−55 to +150							$^{\circ}$

NOTE1:On glass epoxy P.C.B. mounted on 0.05×0.05" (1.3×1.3mm) pads NOTE2:On aluminum substrate P.C.B. with an area of 0.8"  $\times$ 0.8" (20×20mm) mounted on 0.05×0.05" (1.3×1.3mm) solder pad



# MB05F thru MB10F

#### Miniature Glass Passivated Single-Phase Surface Mount Flat Bridge Rectifier

#### Characteristic Curves (T<sub>A</sub>=25 ℃ unless otherwise noted)

Fig.1 Derating Curve For Output **Rectified Current** 0.8 Average Forward Rectified Current (A) 0.7 Aluminium Substrate 0.6 0.5 Glass 0.4 Epoxy P.C.B. 0.3 0.2 0.1 Resistive or Inductive Lode 0 60 90 120 150 30 T<sub>A</sub>--Ambient Temperature (℃)

Fig.3 Typical Forward Voltage Characteristics Per Leg

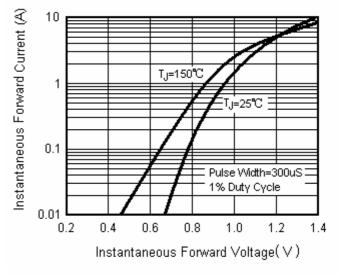


Fig.5 Typical Junction Capacitance Per Leg

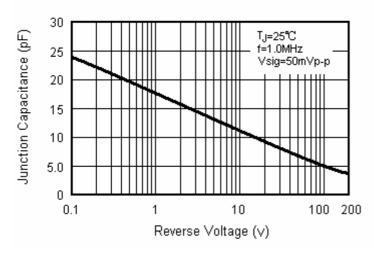


Fig.2 Maximum Non-Repetitive Peak Forward
Surge Current Per Leg

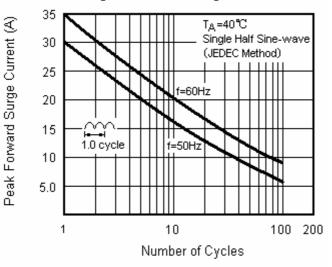


Fig.4 Typical Reverse Leakage Characteristics Per Leg

